

Abstract Submitted
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**Plasmas Sustained by High Repetition Rate Nanosecond Pulses:
Recombination Mechanisms in Ar with H₂O Impurities¹** VLADLEN
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diagnostics was performed for a quasi-steady plasma generated with repetitive
nanosecond pulses at several Torr in argon with H₂O impurity. In this work, a 0-D
kinetic model was developed to understand the recombination between the pulses.
The model included electron energy and continuity equations. In pure argon, both
the electron temperature relaxation and recombination are very slow. The presence
of trace amounts (< 0.1% by volume) of H₂O drastically changes the mechanisms
and rates of recombination and thermalization. Ar⁺ ions are rapidly converted to
H₃O⁺, and the electron losses are primarily due to dissociative recombination with
H₃O⁺. The electron thermalization time is drastically reduced due to excitation of
rotational and vibrational levels of water molecules. The model agrees well with the
experimental data. The results show that generating plasma with high electron den-
sity and low time-averaged electron temperature is possible by combining repetitive
pulses and controlled addition of molecular species to noble gases.

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